

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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HETERO JUNCTION FIELD EFFECT TRANSISTOR NE3510M04

L TO S BAND LOW NOISE AMPLIFIER N-CHANNEL HJ-FET

FEATURES

· Low noise figure and high associated gain

NF = 0.45 dB TYP., G_a = 16 dB TYP. @ f = 4 GHz, V_{DS} = 2 V, I_D = 15 mA NF = 0.35 dB TYP., G_a = 19 dB TYP. @ f = 2 GHz, V_{DS} = 2 V, I_D = 10 mA (Reference only)

• Flat-lead 4-pin thin-type super minimold (M04) package

APPLICATIONS

- · Satellite radio (SDARS, DMB, etc.) antenna LNA
- · Low noise amplifier for microwave communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3510M04	NE3510M04-A	Flat-lead 4-pin	50 pcs (Non reel)	V81	8 mm wide embossed taping
NE3510M04-T2	NE3510M04-T2-A	thin-type super minimold (M04)	3 kpcs/reel		 Pin 1 (Source), Pin 2 (Drain) face the perforation side of the tape
NE3510M04-T2B	NE3510M04-T2B-A	(Pb-Free)	15 kpcs/reel		the perioration side of the tape

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Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: NE3510M04-A

ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	VDS	4.0	V
Gate to Source Voltage	Vgs	-3.0	V
Drain Current	lο	Ioss	mA
Gate Current	lg	140	μΑ
Total Power Dissipation	P _{tot} Note	125	mW
Channel Temperature	Tch	+150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Mounted on 1.08 cm² × 1.0 mm (t) glass epoxy PCB

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Document No. PG10676EJ02V0DS (2nd edition) Date Published October 2008 NS

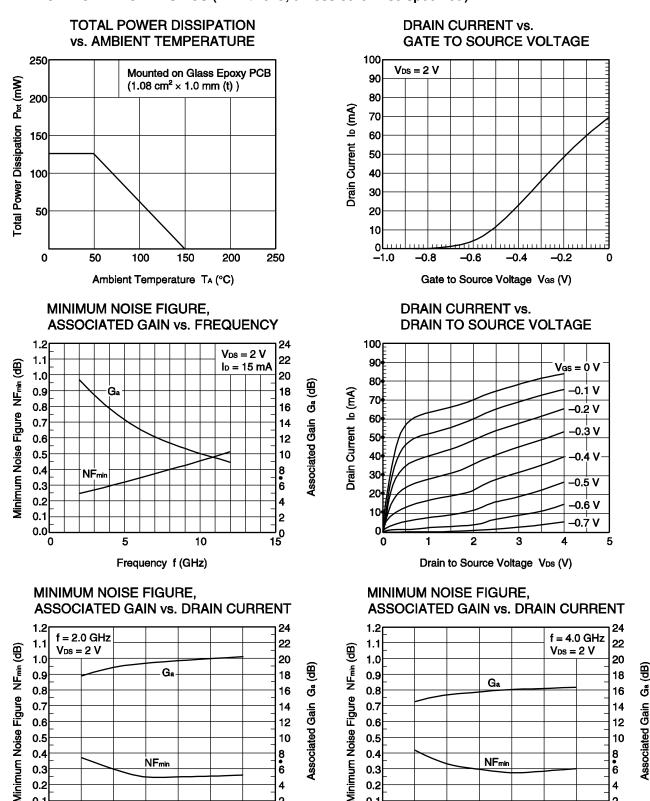
RECOMMENDED OPERATING CONDITIONS (Ta = +25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	VDS	-	2	3	٧
Drain Current	lσ	-	15	30	mA
Input Power	Pin	=	=	0	dBm

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	Igso	Vgs = -3 V	-	0.5	10	μΑ
Saturated Drain Current	IDSS	V _{DS} = 2 V, V _{GS} = 0 V	42	70	97	mA
Gate to Source Cutoff Voltage	V _{GS} (off)	$V_{DS} = 2 \text{ V}, \text{ ID} = 100 \ \mu\text{A}$	-0.35	-0.7	-1.10	V
Transconductance	gm	V _{DS} = 2 V, I _D = 15 mA	70	=	-	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 15 mA, f = 4 GHz	-	0.45	0.65	dB
Associated Gain	Ga		14.5	16	-	dB
Gain 1 dB Compression	Po (1 dB)	$V_{DS} = 2 \text{ V}, I_{D} = 15 \text{ mA (Non-RF)},$	-	+11	-	dBm
Output Power		f = 4 GHz				

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

20•

25

30•

NFmin

15•

Drain Current In (mA)

0.6

0.5

0.4

0.3

0.2

0.1

0.0[

0•

5•

10•

Minimum Noise

12

10

8

6

4

2

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NFmir

Drain Current In (mA)

20.

25•

30.

15•

10•

0.6

0.5

0.4

0.3

0.2

0.1

0.0

0•

5•

12

10

8

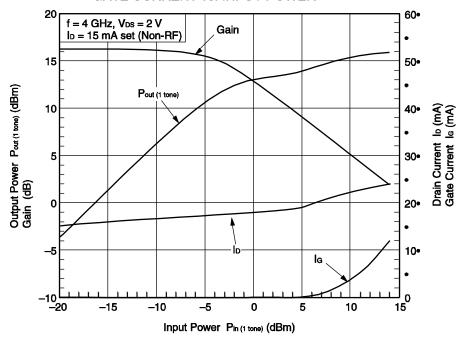
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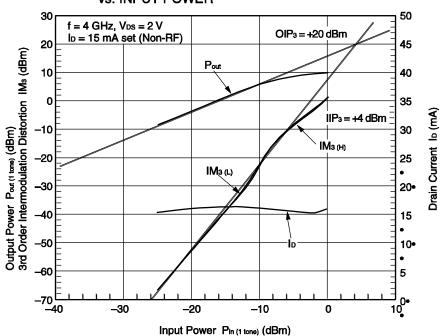
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OUTPUT POWER, GAIN, DRAIN CURRENT, GATE CURRENT vs. INPUT POWER



OUTPUT POWER, IM3, DRAIN CURRENT vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

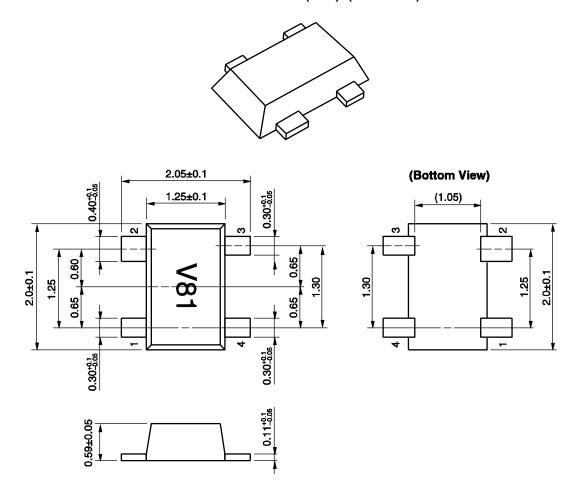
S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

_NE3510M04

PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)

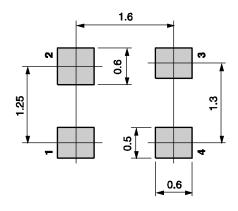


PIN CONNECTIONS

- 1. Source
- 2. Drain
- 3. Source
- 4. Gate

MOUNTING PAD DIMENSIONS (REFERENCE ONLY)

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.